

60 V, N-channel Trench MOSFET 21 March 2016

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic level compatible
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM
- AEC-Q101 qualified

3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quid	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	60	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	-	3.1	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 3.1 A; T _j = 25 °C		-	46	60	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain	1 2 TO-236AB (SOT23)	G S 017aaa255

6. Ordering information

Table 3. Ordering information							
Type number Package							
	Name	Description	Version				
PMV55ENEA	TO-236AB	plastic surface-mounted package; 3 leads	SOT23				

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
PMV55ENEA	DL%

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

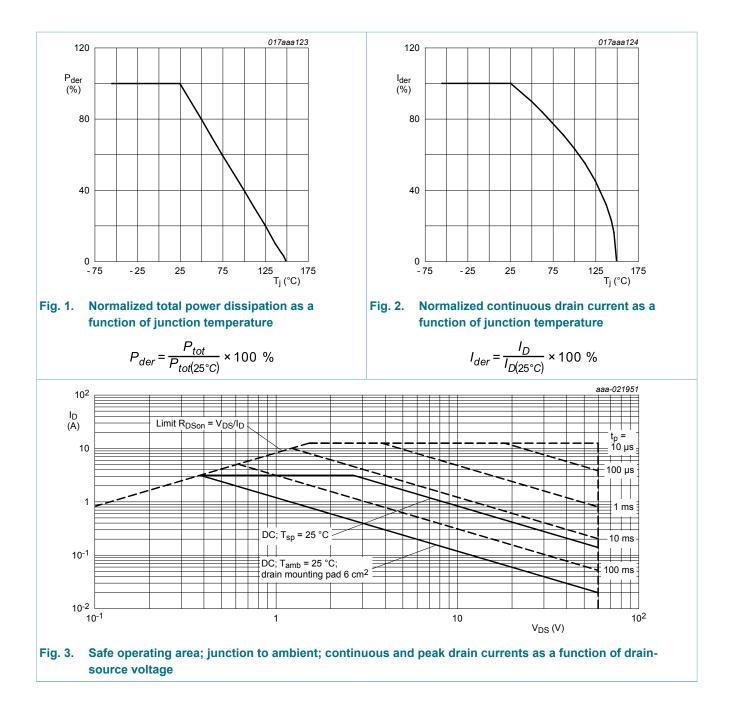
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	60	V
V _{GS}	gate-source voltage	-		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	3.1	А
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	2	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	12.6	А
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$T_{j(init)}$ = 25 °C; I _D = 0.56 A; DUT in avalanche (unclamped)		-	17	mJ
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	478	mW
			[1]	-	1.19	W
		T _{sp} = 25 °C		-	8.36	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	in diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	1.3	А
ESD maxim	um rating					
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	2000	V
	I	1				1

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.

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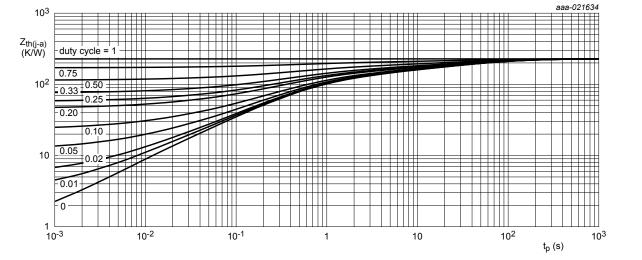


9. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ung a)	thermal resistance	in free air	[1]	-	227	262	K/W
	from junction to ambient		[2]	-	91	105	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	13	15	K/W

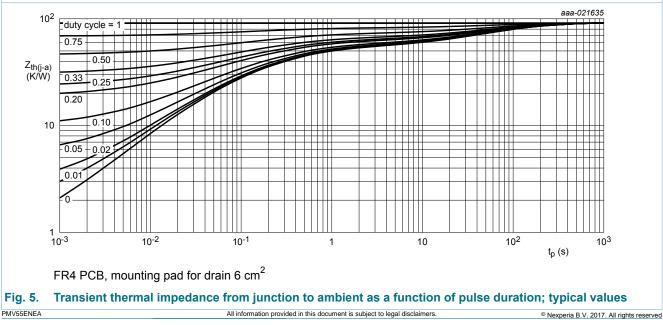
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



FR4 PCB, standard footprint





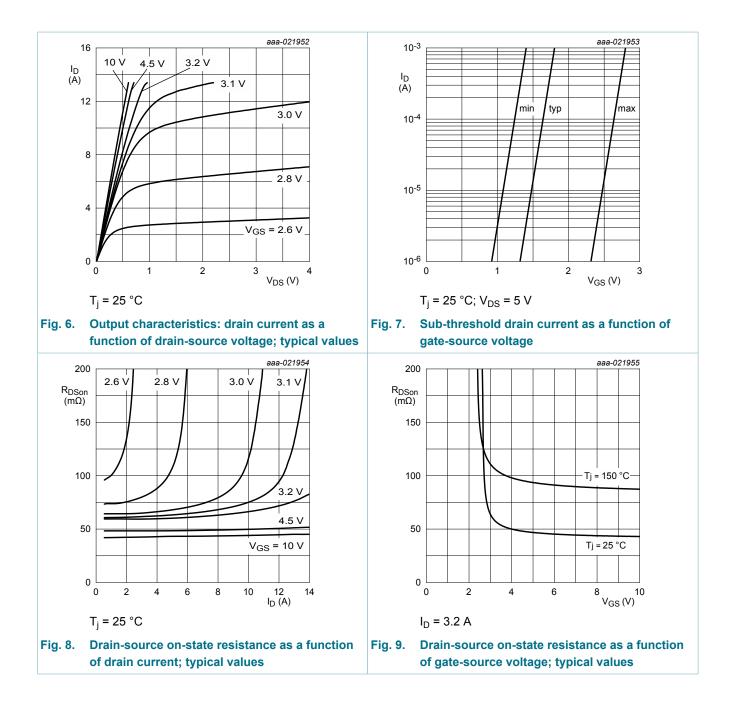
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics	1				
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	60	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	1.3	1.7	2.7	V
I _{DSS}	drain leakage current	V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-1	μA
R _{DSon}	drain-source on-state	V_{GS} = 10 V; I _D = 3.1 A; T _j = 25 °C	-	46	60	mΩ
	resistance	V _{GS} = 10 V; I _D = 3.1 A; T _j = 150 °C	-	92	120	mΩ
		V_{GS} = 4.5 V; I _D = 2.9 A; T _j = 25 °C	-	52	70	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 3.1 A; T _j = 25 °C	-	18.2	-	S
R _G	gate resistance	f = 1 MHz	-	8	-	Ω
Dynamic ch	aracteristics	1	1			
Q _{G(tot)}	total gate charge	V_{DS} = 30 V; I _D = 3.1 A; V _{GS} = 10 V;	-	12.7	19	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.3	-	nC
Q _{GD}	gate-drain charge		-	2.4	-	nC
C _{iss}	input capacitance	V_{DS} = 30 V; f = 1 MHz; V_{GS} = 0 V;	-	646	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	49	-	pF
C _{rss}	reverse transfer capacitance		-	36	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 30 V; I _D = 3.1 A; V _{GS} = 10 V;	-	9	-	ns
t _r	rise time	R _{G(ext)} = 6 Ω; T _j = 25 °C	-	13	-	ns
t _{d(off)}	turn-off delay time		-	33	-	ns
t _f	fall time	-	-	13	-	ns
Source-drai	n diode	1	<u> </u>		1	
V _{SD}	source-drain voltage	I _S = 1.3 A; V _{GS} = 0 V; T _i = 25 °C	-	0.8	1.2	V

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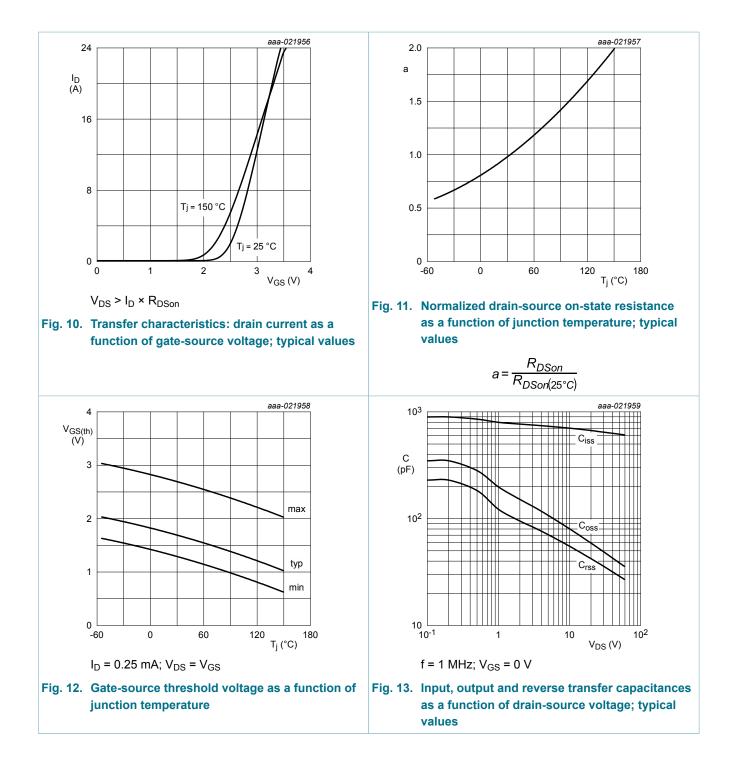


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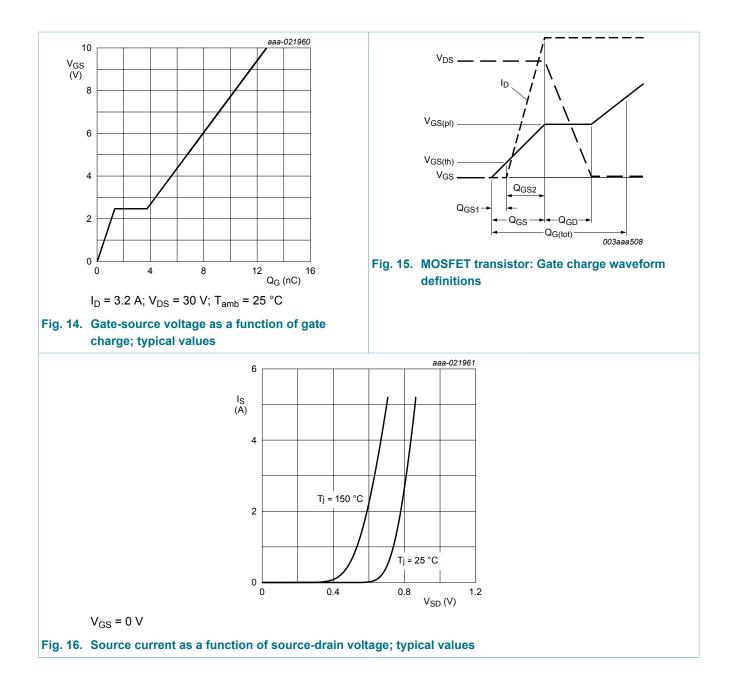
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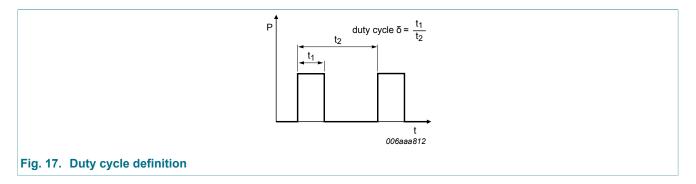
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11. Test information

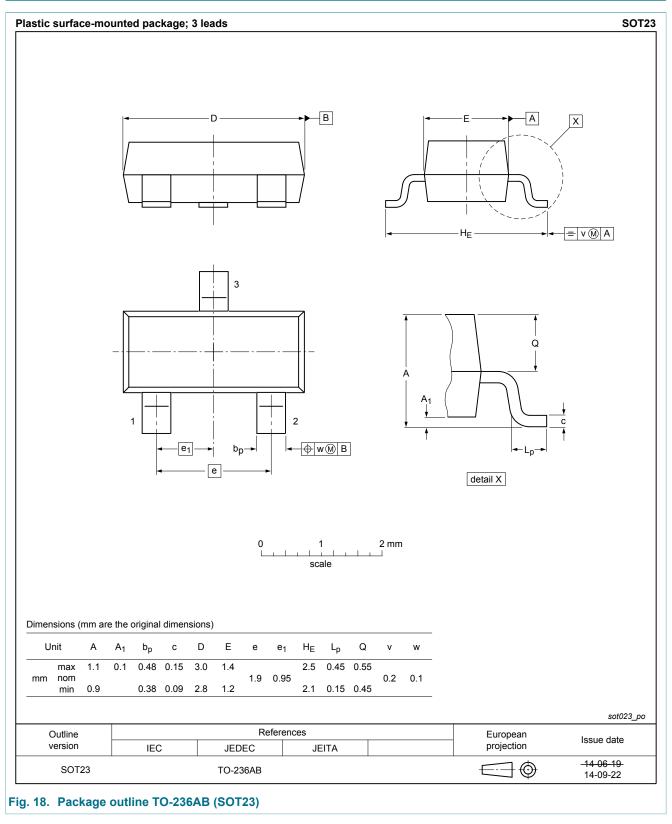


11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

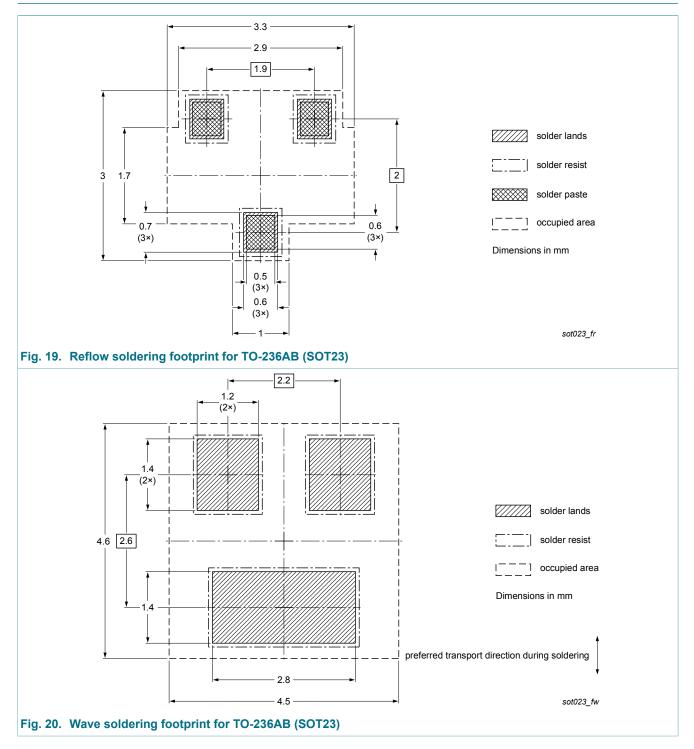
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12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMV55ENEA v.1	20160321	Product data sheet	-	-			

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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